

# STPSC6H065BY-TR

Datasheet

# Automotive 650 V power Schottky silicon carbide diode







### **Features**

- AEC-Q101 qualified
- No reverse recovery charge in application current range
- Switching behavior independent of temperature
- Recommended to PFC applications
- PPAP capable
- ECOPACK<sup>®</sup>2 compliant component

### **Description**

The SiC diode is an ultra-high performance power Schottky diode. It is manufactured using a silicon carbide substrate. The wide band gap material allows the design of a Schottky diode structure with a 650 V rating. Due to the Schottky construction, no recovery is shown at turn-off and ringing patterns are negligible. The minimal capacitive turn-off behavior is independent of temperature.

Especially suited for use in PFC applications, this ST SiC diode will boost performance in hard switching conditions.

Product status		
STPS6H065BY-TR		
Product summary		
Symbol	Value	
I <sub>F(AV)</sub>	6 A	
V <sub>RRM</sub>	650 V	
T <sub>j(max.)</sub>	175 °C	

# 1 Characteristics

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### Table 1. Absolute ratings (limiting values at 25 °C unless otherwise specified)

Symbol	Paran	Value	Unit	
V <sub>RRM</sub>	Repetitive peak reverse voltage $T_j = -40 \text{ °C to } + 175 \text{ °C}$		650	V
I <sub>F(RMS)</sub>	Forward rms current	22	А	
I <sub>F(AV)</sub>	Average forward current	T <sub>c</sub> = 145 °C <sup>(1)</sup> , DC	6	Α
I <sub>FSM</sub>	Surge non repetitive forward current	$t_p$ = 10 ms sinusoidal, T <sub>c</sub> = 25 °C	60	
		$t_p$ = 10 ms sinusoidal, T <sub>c</sub> = 125 °C	52	A
		$t_p$ = 10 µs square, T <sub>c</sub> = 25 °C	400	
I <sub>FRM</sub>	Repetitive peak forward current $T_c = 145 \ ^{\circ}C \ ^{(1)}, T_j = 175 \ ^{\circ}C, \ \delta = 0.1$		23	А
T <sub>stg</sub>	Storage temperature range	-55 to +175	°C	
Tj	Operating junction temperature range <sup>(2)</sup>	-40 to +175	°C	

1. Value based on  $R_{th(j-c)}$  max.

2.  $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$  condition to avoid thermal runaway for a diode on its own heatsink.

#### Table 2. Thermal parameters

Symbol	ymbol Parameter Typ. value		Max. value	Unit
R <sub>th(j-c)</sub>	Junction to case	1.6	2.4	°C/W

#### Table 3. Static electrical characteristics

Symbol	Parameter	Test co	nditions	Min.	Тур.	Max.	Unit
I <sub>R</sub> <sup>(1)</sup>			V <sub>R</sub> = V <sub>RRM</sub>	-	5	60	
'R` '	I <sub>R</sub> <sup>(1)</sup> Reverse leakage current	T <sub>j</sub> = 150 °C	VR − VRRM	-	50	250	μA
V <sub>F</sub> <sup>(2)</sup>	Ecoward voltage drop	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 6 A	-	1.45	1.65	V
<b>v</b> F <sup>(-)</sup>	V <sub>F</sub> <sup>(2)</sup> Forward voltage drop		1 <sub>F</sub> - 0 A	-	1.7	2.05	V

1.  $t_p = 10 \text{ ms}, \delta < 2\%$ 

2.  $t_p = 500 \ \mu s, \ \delta < 2\%$ 

To evaluate the conduction losses, use the following equation:

P = 0.972 x  $I_{F(AV)}$  + 0.180 x  $I_{F}^{2}(RMS)$ 

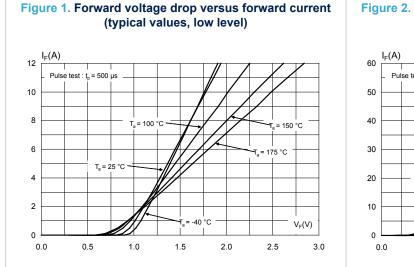
#### Table 4. Dynamic electrical characteristics

Symbol	Parameter	Test conditions	Тур.	Unit
Q <sub>cj</sub> <sup>(1)</sup>	Total capacitive charge	V <sub>R</sub> = 400 V	18	nC
Ci		$V_{R}$ = 0 V, T <sub>c</sub> = 25 °C, F = 1 MHz	300	ъĘ
Cj	Total capacitance	$V_{R}$ = 400 V, $T_{c}$ = 25 °C, F = 1 MHz	30	pF

<sup>1</sup>. Most accurate value for the capacitive charge:  $Q_{cj} = \int_0^{V_{OUT}} c_j(V_R) \times d_{VR}$ 



### 1.1 Characteristics (curves)





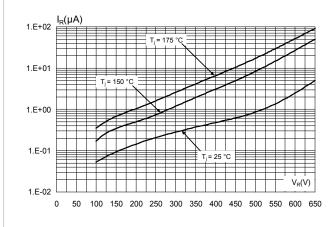
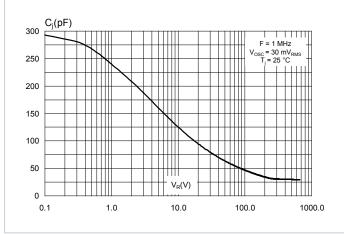


Figure 5. Junction capacitance versus reverse voltage applied (typical values)



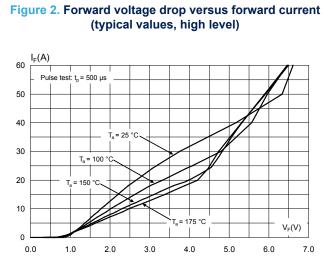


Figure 4. Peak forward current versus case temperature

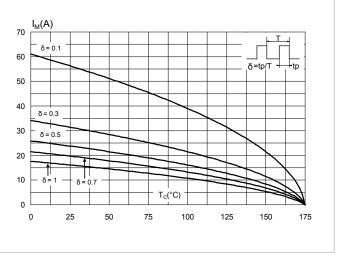
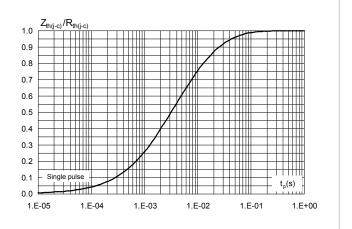
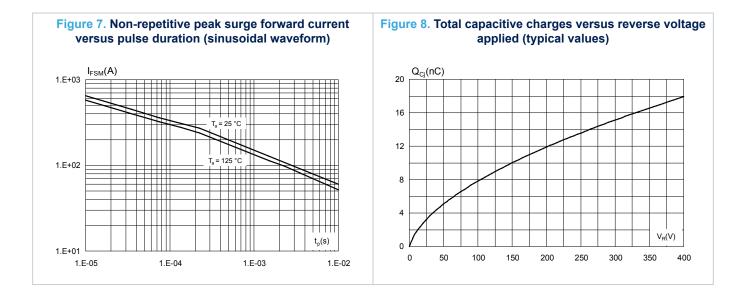


Figure 6. Relative variation of thermal impedance junction to case versus pulse duration





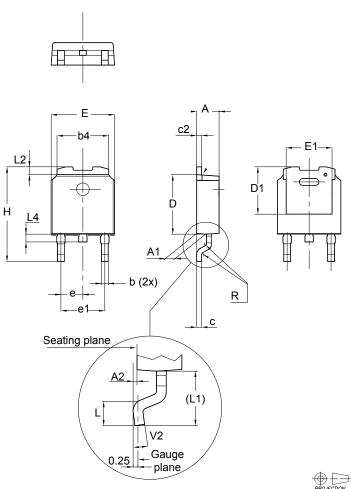


# 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: www.st.com. ECOPACK<sup>®</sup> is an ST trademark.

## 2.1 DPAK package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)

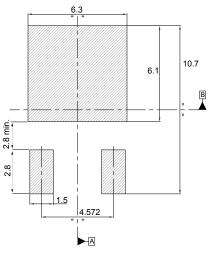


### Figure 9. DPAK package outline

	Dimensions					
Dim.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	2.20		2.40	0.087		0.094
A1	0.90		1.10	0.035		0.043
A2	0.03		0.23	0.001		0.009
b	0.64		0.90	0.025		0.035
b4	5.20		5.40	0.205		0.213
С	0.45		0.60	0.018		0.024
c2	0.48		0.60	0.019		0.024
D	6.00		6.20	0.236		0.244
D1	4.95	5.10	5.25	0.195	0.201	0.207
E	6.40		6.60	0.252		0.260
E1	4.60	4.70	4.80	0.181	0.185	0.189
е	2.16	2.28	2.40	0.085	0.090	0.094
e1	4.40		4.60	0.173		0.181
Н	9.35		10.10	0.368		0.398
L	1.00		1.50	0.039		0.059
(L1)	2.60	2.80	3.00	0.102	0.110	0.118
L2	0.65	0.80	0.95	0.026	0.031	0.037
L4	0.60		1.00	0.024		0.039
R		0.20			0.008	
V2	0°		8°	0°		8°

#### Table 5. DPAK mechanical data

### Figure 10. DPAK recommended footprint (dimensions are in mm)



The device must be positioned within  $\fbox{(0.05]AB}$ 

DS12494 - Rev 1		
Downloaded from	Arrow.com.	



# **3** Ordering Information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPSC6H065BY-TR	PSC6H 065Y	DPAK	0.32 g	2500	Tape and reel

### Table 6. Ordering information

## **Revision history**

#### Table 7. Document revision history

Date	Version	Changes
13-Mar-2018	1	Initial release.



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